

L Number	Hits	Search Text	DB	Time stamp
1	4297	(257/59,57, 66, 72, "347").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 17:26

L Number	Hits	Search Text	DB	Time stamp
1	2589	(257/344, 408, 412, "413").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 17:47

L Number	Hits	Search Text	DB	Time stamp
1	21929	semiconductor and (tft or (thin adj film adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/08 15:56
2	1869	((semiconductor and (tft or (thin adj film adj transistor))) and (ldd or (lightly adj doped adj drain)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/08 16:08
3	1593	((semiconductor and (tft or (thin adj film adj transistor))) and (ldd or (lightly adj doped adj drain))) and (gate adj electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/08 16:08
4	343	((semiconductor and (tft or (thin adj film adj transistor))) and (ldd or (lightly adj doped adj drain))) and (gate adj electrode)) and taper\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/08 16:08